

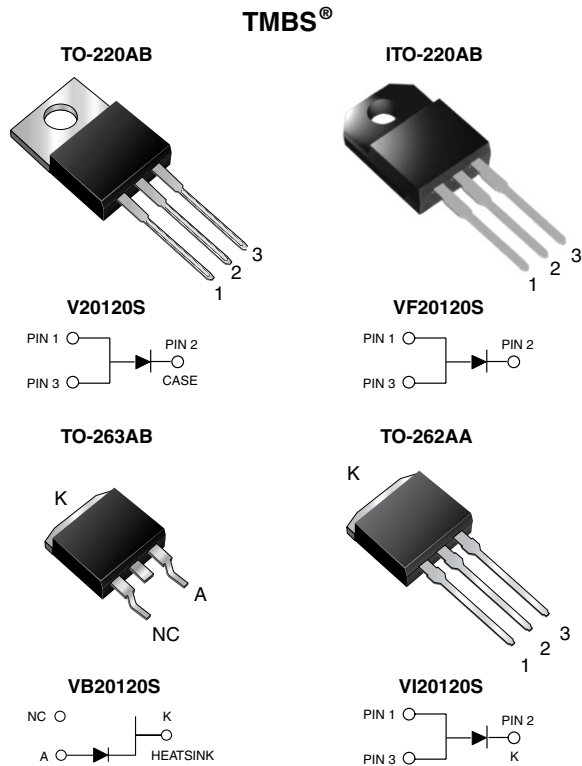


**New Product**  
**V20120S, VF20120S, VB20120S & VI20120S**

Vishay General Semiconductor

## High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.50\text{ V}$  at  $I_F = 5\text{ A}$



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020C, LF max peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 seconds (for TO-220AB, ITO-220AB & TO-262AA package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, free-wheeling diodes, oring diode, dc-to-dc converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB & TO-262AA

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

| PRIMARY CHARACTERISTICS      |        |
|------------------------------|--------|
| $I_{F(AV)}$                  | 20 A   |
| $V_{RRM}$                    | 120 V  |
| $I_{FSM}$                    | 200 A  |
| $V_F$ at $I_F = 20\text{ A}$ | 0.73 V |
| $T_J$ max.                   | 150 °C |

| MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)                     |                |               |          |          |          |      |
|--|----------------|---------------|----------|----------|----------|------|
| PARAMETER  | SYMBOL         | V20120S       | VF20120S | VB20120S | VI20120S | UNIT |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$      | 120           |          |          |          | V    |
| Maximum average forward rectified current (see Fig. 1)                             | $I_{F(AV)}$    | 20            |          |          |          | A    |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | $I_{FSM}$      | 200           |          |          |          | A    |
| Isolation voltage (ITO-220AB only)<br>From terminal to heatsink $t = 1$ minute     | $V_{AC}$       | 1500          |          |          |          | V    |
| Operating junction and storage temperature range                                   | $T_J, T_{STG}$ | - 40 to + 150 |          |          |          | °C   |

| ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |   |                         |                   |               |      |      |
|--|---|-------------------------|-------------------|---------------|------|------|
| PARAMETER  | TEST CONDITIONS   |                         | SYMBOL            | TYP.          | MAX. | UNIT |
| Breakdown voltage  | at I <sub>R</sub> = 1.0 mA  | T <sub>A</sub> = 25 °C  | V <sub>(BR)</sub> | 120 (minimum) | -    | V    |
| Instantaneous forward voltage <sup>(1)</sup>                               | at I <sub>F</sub> = 5 A<br>I <sub>F</sub> = 10 A<br>I <sub>F</sub> = 20 A | T <sub>A</sub> = 25 °C  | V <sub>F</sub>    | 0.57          | -    |      |
|  |   |                         |                   | 0.71          | -    |      |
|  |   | 0.99                    |                   | 1.12          |      |      |
|  |   | T <sub>A</sub> = 125 °C |                   | 0.50          | -    |      |
|  |   |                         | 0.61              | -             |      |      |
|  |   |                         | 0.73              | 0.81          |      |      |
| Reverse current <sup>(2)</sup>   | at V <sub>R</sub> = 90 V  | T <sub>A</sub> = 25 °C  | I <sub>R</sub>    | 10            | -    | μA   |
|  |   | T <sub>A</sub> = 125 °C |                   | 6             | -    | mA   |
|  | at V <sub>R</sub> = 120 V   | T <sub>A</sub> = 25 °C  |                   | -             | 300  | μA   |
|  |   | T <sub>A</sub> = 125 °C | 14                | 30            | mA   |      |

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: 10 ms pulse width

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                  |         |          |          |          |      |
|---|------------------|---------|----------|----------|----------|------|
| PARAMETER   | SYMBOL           | V20120S | VF20120S | VB20120S | VI20120S | UNIT |
| Typical thermal resistance  | R <sub>θJC</sub> | 2       | 4        | 2        | 2        | °C/W |

| ORDERING INFORMATION (Example) |                |                 |              |               |               |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | V20120S-E3/4W  | 1.88            | 4W           | 50/tube       | Tube          |
| ITO-220AB                      | VF20120S-E3/4W | 1.75            | 4W           | 50/tube       | Tube          |
| TO-263AB                       | VB20120S-E3/4W | 1.38            | 4W           | 50/tube       | Tube          |
| TO-263AB                       | VB20120S-E3/8W | 1.38            | 8W           | 800/reel      | Tape and reel |
| TO-262AA                       | VI20120S-E3/4W | 1.45            | 4W           | 50/tube       | Tube          |

RATINGS AND CHARACTERISTICS CURVES

(T<sub>A</sub> = 25 °C unless otherwise noted)

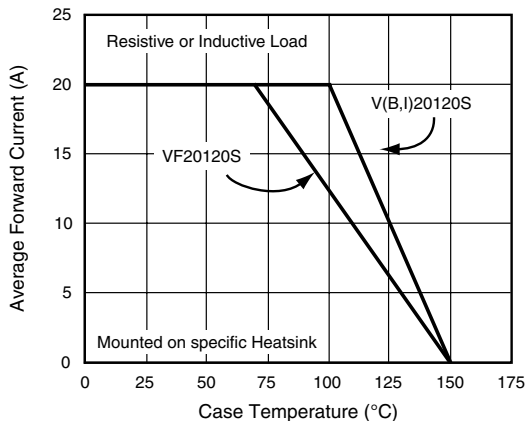


Figure 1. Maximum Forward Current Derating Curve

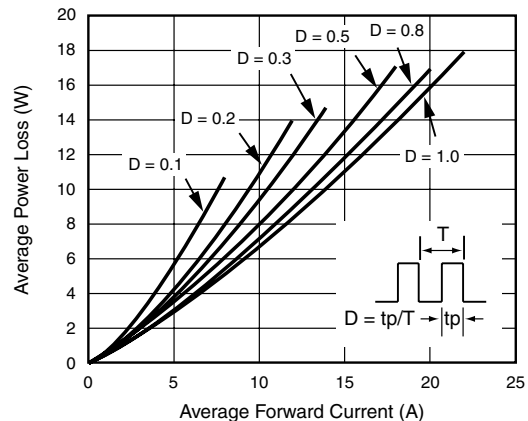


Figure 2. Forward Power Loss Characteristics



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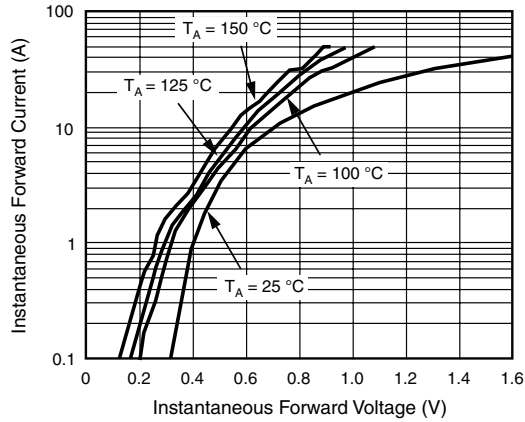


Figure 3. Typical Instantaneous Forward Characteristics

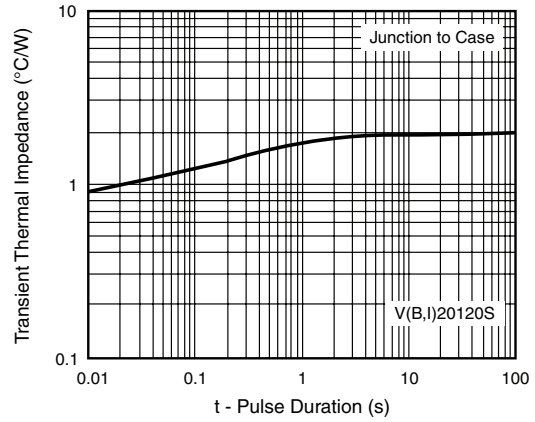


Figure 6. Typical Transient Thermal Impedance

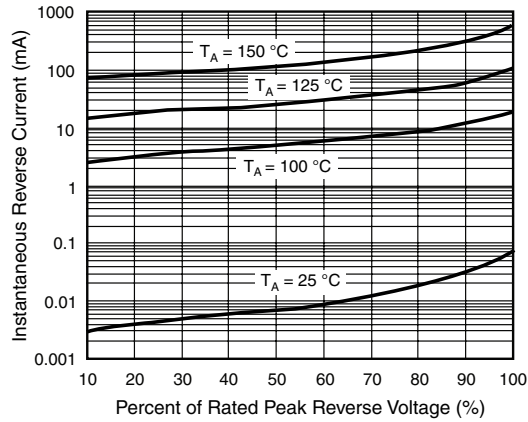


Figure 4. Typical Reverse Characteristics

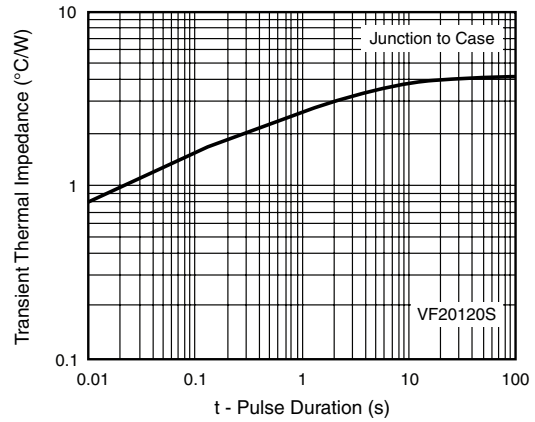


Figure 7. Typical Transient Thermal Impedance

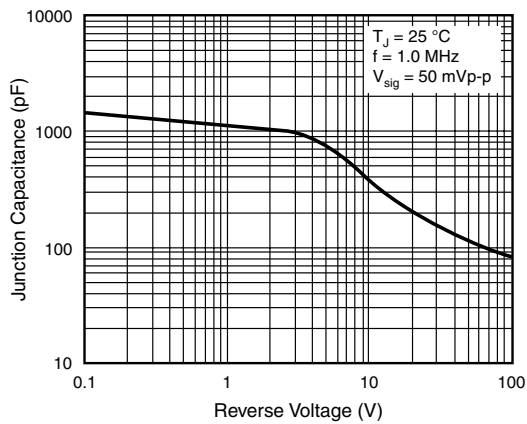
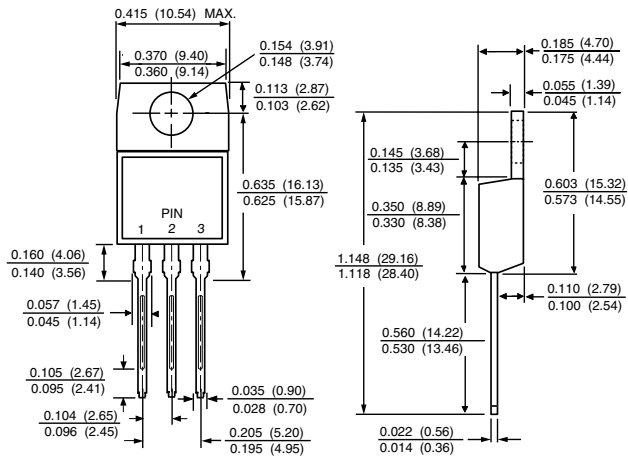


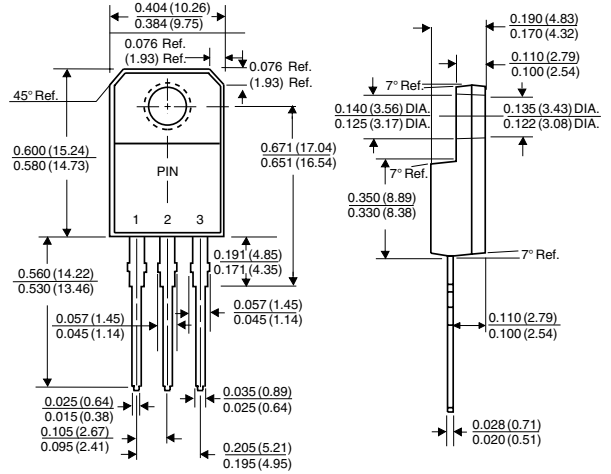
Figure 5. Typical Junction Capacitance

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

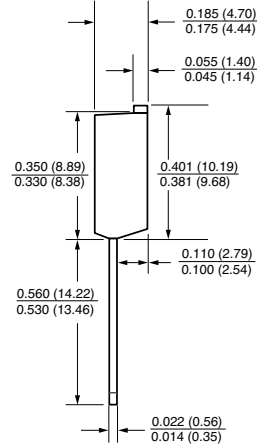
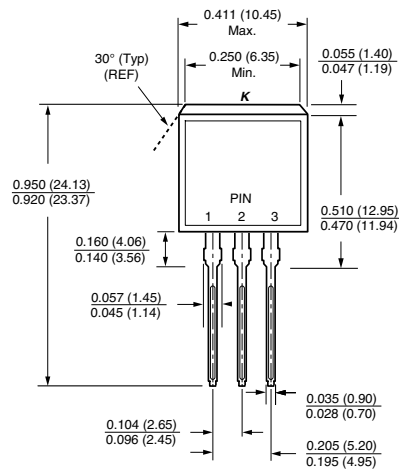
TO-220AB



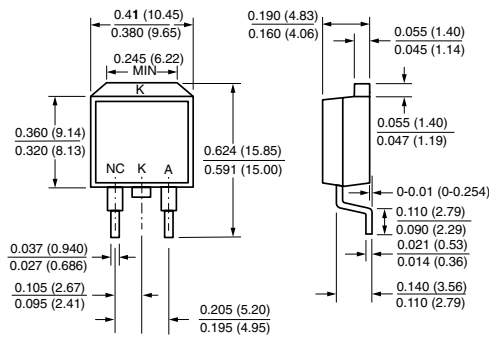
ITO-220AB



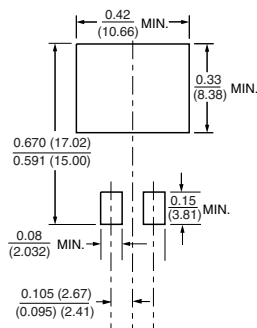
TO-262AA



TO-263AB



Mounting Pad Layout





## Notice

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